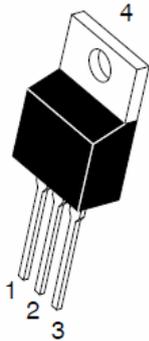
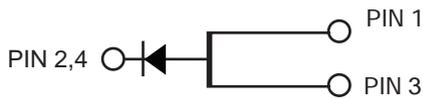
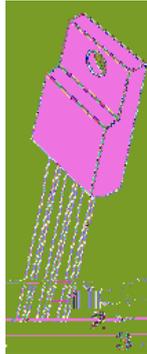


Trench MOS Barrier Schottky Rectifier

TO-220AB
TSR10L100CT-S



ITO-220AB
TSR10L100CTF-S



Features

- Advanced trench technology
- Low forward voltage drop
- Low power losses
- High efficiency operation
- Lead Free Finish, RoHS Compliant

Applications

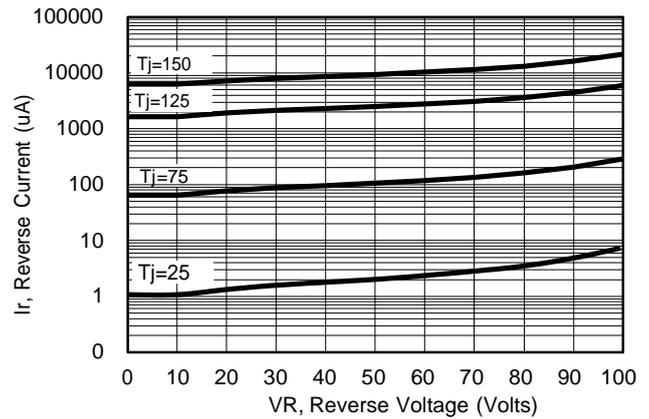
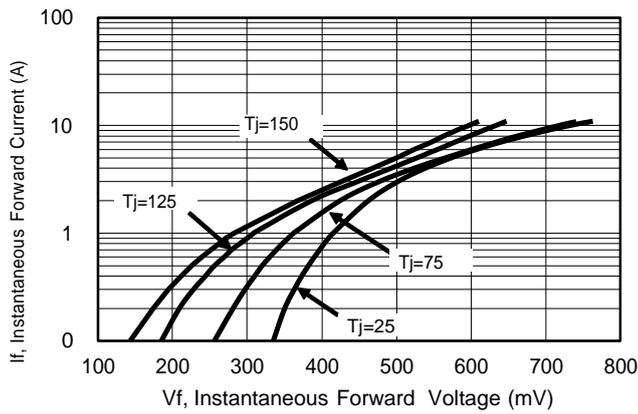
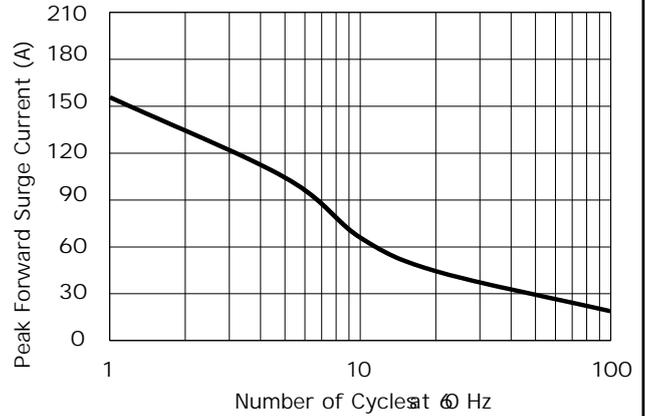
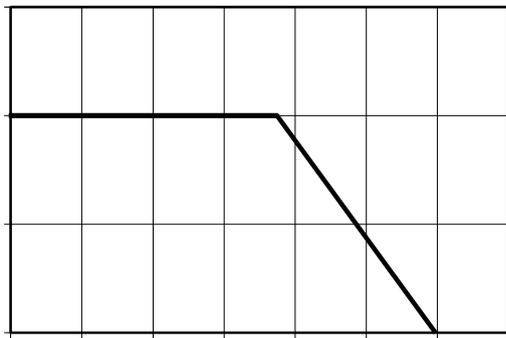
- DC/DC Converters
- AC/DC Adaptors
- Switching Power Supplies
- Freewheeling Diodes

Maximum ratings and electrical characteristics (T_J = 25°C unless otherwise noted)

| Parameter | | Symbol | Limit | | Unit | |
|---|------------|-----------|-------------|------|------|----|
| Maximum repetitive peak reverse voltage | | VRRM | 1 0 | | V | |
| Maximum average forward rectified current | per device | IF(AV) | 10 | | A | |
| Peak forward surge current 8.3 ms single half sine- wave superimposed on rated load per diode | | IFSM | 0 | | A | |
| Operating junction and storage temperature range | | TJ, TSTG | -55 to +150 | | °C | |
| Typical thermal resistance per leg | | TO-220AB | 2 | | °C/W | |
| | | ITO-220AB | 4 | | °C/W | |
| Instantaneous forward voltage per diode | | | TYP. | MAX. | V | |
| | IF=2A | TJ=25°C | 0. | | | |
| | IF=2A | TJ=125°C | | - | | |
| | IF=10A | TJ=25°C | | | | |
| Instantaneous reverse current per diode at rated reverse voltage | | | 0. 8 | - | | |
| | | | - | 0 | µA | |
| | | | | - | 10 | mA |

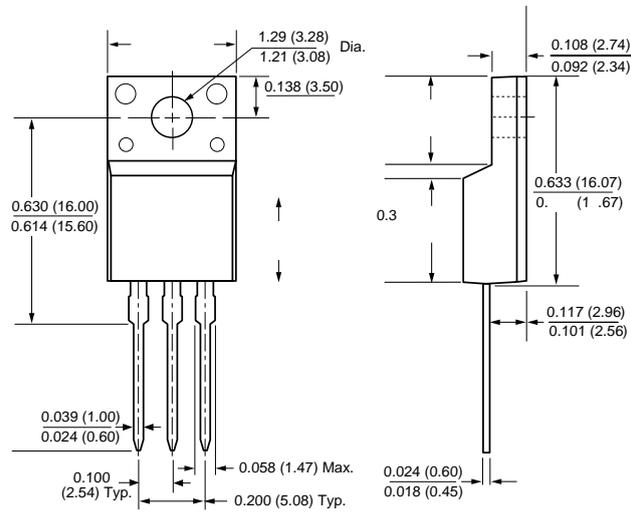
Notes:

RATINGS AND CHARACTERISTICS CURVES



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PACKAGE OUTLINE DIMENSIONS



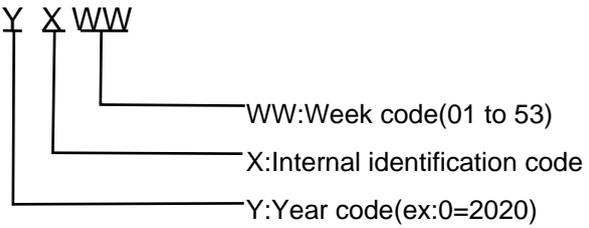
Marking Information

①W : Company's trademark

②Product model : TSR10 OCT 10 0

③PDC information

Y X WW



Packaging Information

1.Tube Dimensions

2.Inside Box

3.Outside Box

Packaging Information

| NO | UNIT | Tube Dimensions | | Inside Box | Outside Box |
|------|------|-----------------|---|------------|-------------|
| | | A | B | | |
| Size | mm | | | | |